

FEATURES

- ±2 V to ±6 V dual supply
- 2 V to 12 V single supply
- Automotive temperature range -40°C to $+125^{\circ}\text{C}$
- <0.1 nA leakage currents
- 45 Ω on resistance over full signal range
- Rail-to-rail switching operation
- Single 8-to-1 multiplexer **ADG658**
- Differential 4-to-1 multiplexer **ADG659**
- 16-lead LFCSP/TSSOP/QSOP packages
- Typical power consumption <0.1 μW
- TTL/CMOS compatible inputs
- Package upgrades to 74HC4051/74HC4052 and
MAX4051/MAX4052/MAX4581/MAX4582

APPLICATIONS

- Automotive applications
- Automatic test equipment
- Data acquisition systems
- Battery-powered systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Sample-and-hold systems
- Industrial control systems

GENERAL DESCRIPTION

The **ADG658** and **ADG659** are low voltage, CMOS analog multiplexers comprised of eight single channels and four differential channels, respectively. The **ADG658** switches one of eight inputs (S1–S8) to a common output, D, as determined by the 3-bit binary address lines A0, A1, and A2. The **ADG659** switches one of four differential inputs to a common differential output, as determined by the 2-bit binary address lines A0 and A1. An $\overline{\text{EN}}$ input on both devices enables or disables the device. When disabled, all channels are switched off.

These devices are designed on an enhanced process that provides lower power dissipation yet gives high switching speeds. These devices can operate equally well as either multiplexers or demultiplexers and have an input range that extends to the supplies. All channels exhibit break-before-make switching action, preventing momentary shorting when switching channels. All digital inputs have 0.8 V to 2.4 V logic thresholds, ensuring TTL/CMOS logic compatibility when using single +5 V or dual ± 5 V supplies.

FUNCTIONAL BLOCK DIAGRAM

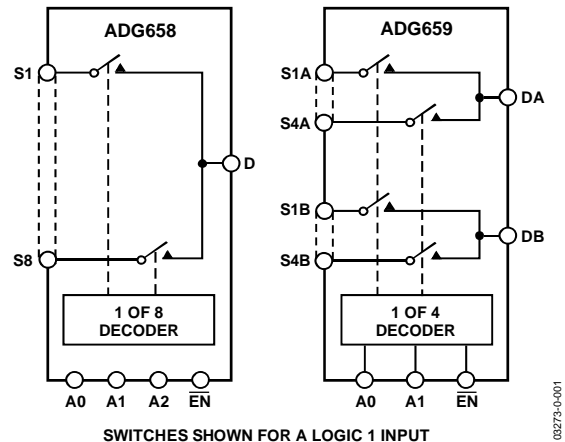


Figure 1.

The **ADG658** and **ADG659** are available in 16-lead TSSOP/QSOP packages and 16-lead 4 mm × 4 mm LFCSP packages.

PRODUCT HIGHLIGHTS

1. Single- and dual-supply operation. The **ADG658** and **ADG659** offer high performance and are fully specified and guaranteed with ± 5 V, +5 V, and +3 V supply rails.
2. Automotive temperature range -40°C to $+125^{\circ}\text{C}$.
3. Low power consumption, typically <0.1 μW .
4. 16-lead 4 mm × 4 mm LFCSP packages, 16-lead TSSOP package and 16-lead QSOP package.

Rev. D

[Document Feedback](#)

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

TABLE OF CONTENTS

| | | | |
|-----------------------------------|---|--|----|
| Features | 1 | Absolute Maximum Ratings | 9 |
| Applications..... | 1 | ESD Caution..... | 9 |
| Functional Block Diagram | 1 | Pin Configurations and Function Descriptions | 11 |
| General Description | 1 | Typical Performance Characteristics | 12 |
| Product Highlights | 1 | Terminology | 15 |
| Revision History | 2 | Test Circuits..... | 16 |
| Specifications..... | 3 | Outline Dimensions | 19 |
| Dual Supply | 3 | Ordering Guide | 20 |
| 5 V Single Supply..... | 5 | Automotive Products..... | 20 |
| 2.7 V to 3.6 V Single Supply..... | 7 | | |

REVISION HISTORY

11/2016—Rev. C to Rev. D

| | |
|--------------------------------------|----|
| Changes to Figure 3 and Table 7..... | 11 |
| Updated Outline Dimensions | 19 |
| Changes to Ordering Guide | 20 |

9/2014—Rev. B to Rev. C

| | |
|----------------------------------|----|
| Moved Terminology Section..... | 15 |
| Updated Outline Dimensions | 19 |
| Changes to Ordering Guide | 20 |

2/2009—Rev. A to Rev. B

| | |
|---------------------------------|----|
| Changes to Ordering Guide | 20 |
|---------------------------------|----|

7/2004—Rev. 0 to Rev. A

| | |
|----------------------------------|-----------|
| Updated Format..... | Universal |
| Added QSOP Package Outline | 20 |
| Changes to Ordering Guide | 20 |
| 3/03—Rev. 0: Initial Version | |

SPECIFICATIONS

DUAL SUPPLY

$V_{DD} = +5\text{ V} \pm 10\%$, $V_{SS} = -5\text{ V} \pm 10\%$, GND = 0 V, unless otherwise noted.

Table 1.

| Parameter | B Version | | | Y Version | | Unit | Test Conditions/Comments |
|--|-------------|-------------------|--------------------|----------------------|-------------------|---|--------------------------|
| | +25°C | -40°C to +85°C | -40°C to +125°C | -40°C to +125°C | | | |
| ANALOG SWITCH | | | | | | | |
| Analog Signal Range | | | | V_{SS} to V_{DD} | V | $V_{DD} = +4.5\text{ V}$, $V_{SS} = -4.5\text{ V}$ | |
| On Resistance (R_{ON}) | 45 | | | | Ω typ | $V_S = \pm 4.5\text{ V}$, $I_S = 1\text{ mA}$; see Figure 21 | |
| | 75 | 90 | | 100 | Ω max | | |
| On Resistance Match between Channels (ΔR_{ON}) | 1.3 | | | | Ω typ | $V_S = 3.5\text{ V}$, $I_S = 1\text{ mA}$ | |
| | 3 | 3.2 | | 3.5 | Ω max | $V_{DD} = +5\text{ V}$, $V_{SS} = -5\text{ V}$; | |
| On Resistance Flatness ($R_{FLAT(ON)}$) | 10 | | | | Ω typ | $V_S = \pm 3\text{ V}$, $I_S = 1\text{ mA}$ | |
| | 16 | 17 | | 18 | Ω max | | |
| LEAKAGE CURRENTS | | | | | | | |
| Source OFF Leakage I_S (OFF) | ± 0.005 | | | | nA typ | $V_{DD} = +5.5\text{ V}$, $V_{SS} = -5.5\text{ V}$ | |
| | ± 0.2 | | | ± 5 | nA max | $V_D = \pm 4.5\text{ V}$, $V_S = \mp 4.5\text{ V}$; see Figure 22 | |
| Drain OFF Leakage I_D (OFF) | ± 0.005 | | | | nA typ | $V_D = \pm 4.5\text{ V}$, $V_S = \mp 4.5\text{ V}$; see Figure 23 | |
| ADG658 | ± 0.2 | | | ± 5 | nA max | | |
| ADG659 | ± 0.1 | | | ± 2.5 | nA max | | |
| Channel ON Leakage I_D , I_S (ON) | ± 0.005 | | | | nA typ | $V_D = V_S = \pm 4.5\text{ V}$; see Figure 24 | |
| ADG658 | ± 0.2 | | | ± 5 | nA max | | |
| ADG659 | ± 0.1 | | | ± 2.5 | nA max | | |
| DIGITAL INPUTS | | | | | | | |
| Input High Voltage, V_{INH} | | | | 2.4 | V min | | |
| Input Low Voltage, V_{INL} | | | | 0.8 | V max | | |
| Input Current | | | | | | | |
| I_{INL} or I_{INH} | 0.005 | | | | μA typ | $V_{IN} = V_{INL}$ or V_{INH} | |
| | | | | ± 1 | μA max | | |
| C_{IN} , Digital Input Capacitance | 2 | | | | pF typ | | |
| DYNAMIC CHARACTERISTICS ¹ | | | | | | | |
| $t_{TRANSITION}$ | 80 | | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ | |
| | 115 | 140 | | 165 | ns max | $V_S = 3\text{ V}$; see Figure 25 | |
| $t_{ON}(\overline{EN})$ | 80 | | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ | |
| | 115 | 140 | | 165 | ns max | $V_S = 3\text{ V}$; see Figure 27 | |
| $t_{OFF}(\overline{EN})$ | 30 | | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ | |
| | 45 | 50 | | 55 | ns max | $V_S = 3\text{ V}$; see Figure 27 | |
| Break-Before-Make Time Delay, t_{BBM} | 50 | | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ | |
| | | | | 10 | ns min | $V_{S1} = V_{S2} = 3\text{ V}$; see Figure 26 | |
| Charge Injection | 2 | | | | pC typ | $V_S = 0\text{ V}$, $R_S = 0\ \Omega$, | |
| | 4 | | | | pC max | $C_L = 1\text{ nF}$; see Figure 28 | |
| Off Isolation | -90 | | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; see Figure 29 | |
| Total Harmonic Distortion, THD + N | 0.025 | | | | % typ | $R_L = 600\ \Omega$, 2 V p-p, $f = 20\text{ Hz}$ to 20 kHz | |
| Channel-to-Channel Crosstalk (ADG659) | -90 | | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; see Figure 31 | |
| -3 dB Bandwidth | | | | | | | |
| ADG658 | 210 | | | | MHz typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; see Figure 30 | |
| ADG659 | 400 | | | | MHz typ | | |

| Parameter | +25°C | B Version | Y Version | Unit | Test Conditions/Comments |
|--------------------------------------|-------|-------------------|--------------------|--------|---|
| | | –40°C to +85°C | –40°C to +125°C | | |
| C _S (OFF) | 4 | | | pF typ | f = 1 MHz |
| C _D (OFF) | | | | | |
| ADG658 | 23 | | | pF typ | f = 1 MHz |
| ADG659 | 12 | | | pF typ | f = 1 MHz |
| C _D , C _S (ON) | | | | | |
| ADG658 | 28 | | | pF typ | f = 1 MHz |
| ADG659 | 16 | | | pF typ | f = 1 MHz |
| POWER REQUIREMENTS | | | | | |
| I _{DD} | 0.01 | | | μA typ | V _{DD} = +5.5 V, V _{SS} = –5.5 V Digital Inputs = 0 V or 5.5 V |
| | | | 1 | μA max | |
| I _{SS} | 0.01 | | | μA typ | Digital Inputs = 0 V or 5.5 V |
| | | | 1 | μA max | |

¹ Guaranteed by design; not subject to production test.

5 V SINGLE SUPPLY

$V_{DD} = 5\text{ V} \pm 10\%$, $V_{SS} = 0\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.

Table 2.

| Parameter | B Version | | | Y Version | | Unit | Test Conditions/Comments |
|--|-------------|-------------------|--------------------|--------------------|--------------------|-------------------|--|
| | +25°C | -40°C to +85°C | -40°C to +125°C | -40°C to +125°C | -40°C to +125°C | | |
| ANALOG SWITCH | | | | | | | |
| Analog Signal Range | | | | 0 to V_{DD} | | V | $V_{DD} = 4.5\text{ V}$, $V_{SS} = 0\text{ V}$ |
| On Resistance (R_{ON}) | 85 | | | | | Ω typ | $V_S = 0\text{ V}$ to 4.5 V , $I_S = 1\text{ mA}$; see Figure 21 |
| | 150 | 160 | 200 | | | Ω max | |
| On Resistance Match between Channels (ΔR_{ON}) | 4.5 | | | | | Ω typ | $V_S = 3.5\text{ V}$, $I_S = 1\text{ mA}$ |
| | 8 | 9 | 10 | | | Ω max | |
| On Resistance Flatness ($R_{FLAT(ON)}$) | 13 | 14 | 16 | | | Ω typ | $V_{DD} = 5\text{ V}$, $V_{SS} = 0\text{ V}$, $V_S = 1.5\text{ V}$ to 4 V , $I_S = 1\text{ mA}$ |
| LEAKAGE CURRENTS | | | | | | | |
| Source OFF Leakage I_S (OFF) | ± 0.005 | | | | | nA typ | $V_{DD} = 5.5\text{ V}$ |
| | ± 0.2 | | | ± 5 | | nA max | $V_S = 1\text{ V}/4.5\text{ V}$, $V_D = 4.5\text{ V}/1\text{ V}$; see Figure 22 |
| Drain OFF Leakage I_D (OFF) | ± 0.005 | | | | | nA typ | $V_S = 1\text{ V}/4.5\text{ V}$, $V_D = 4.5\text{ V}/1\text{ V}$; see Figure 23 |
| ADG658 | ± 0.2 | | | ± 5 | | nA max | |
| ADG659 | ± 0.1 | | | ± 2.5 | | nA max | |
| Channel ON Leakage I_D , I_S (ON) | ± 0.005 | | | | | nA typ | $V_S = V_D = 1\text{ V}$ or 4.5 V , see Figure 24 |
| ADG658 | ± 0.2 | | | ± 5 | | nA max | |
| ADG659 | ± 0.1 | | | ± 2.5 | | nA max | |
| DIGITAL INPUTS | | | | | | | |
| Input High Voltage, V_{INH} | | | | 2.4 | | V min | |
| Input Low Voltage, V_{INL} | | | | 0.8 | | V max | |
| Input Current | | | | | | | |
| I_{INL} or I_{INH} | 0.005 | | | | | μA typ | $V_{IN} = V_{INL}$ or V_{INH} |
| | | | | ± 1 | | μA max | |
| C_{IN} , Digital Input Capacitance | 2 | | | | | pF typ | |
| DYNAMIC CHARACTERISTICS¹ | | | | | | | |
| $t_{TRANSITION}$ | 120 | | | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ |
| | 200 | 270 | 300 | | | ns max | $V_S = 3\text{ V}$; see Figure 25 |
| $t_{ON}(\overline{EN})$ | 120 | | | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ |
| | 190 | 245 | 280 | | | ns max | $V_S = 3\text{ V}$; see Figure 27 |
| $t_{OFF}(\overline{EN})$ | 35 | | | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ |
| | 50 | 60 | 70 | | | ns max | $V_S = 3\text{ V}$; see Figure 27 |
| Break-Before-Make Time Delay, t_{BBM} | 100 | | | | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$ |
| | | | | 10 | | ns min | $V_{S1} = V_{S2} = 3\text{ V}$; see Figure 26 |
| Charge Injection | 0.5 | | | | | pC typ | $V_S = 2.5\text{ V}$, $R_S = 0\ \Omega$, $C_L = 1\text{ nF}$; see Figure 28 |
| | 1 | | | | | pC max | |
| Off Isolation | -90 | | | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; see Figure 29 |
| Channel-to-Channel Crosstalk | -90 | | | | | dB typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; $f = 1\text{ MHz}$; see Figure 31 |
| (ADG659) | | | | | | | |
| -3 dB Bandwidth | | | | | | | |
| ADG658 | 180 | | | | | MHz typ | $R_L = 50\ \Omega$, $C_L = 5\text{ pF}$; see Figure 30 |
| ADG659 | 330 | | | | | MHz typ | |
| C_S (OFF) | 5 | | | | | pF typ | $f = 1\text{ MHz}$ |
| C_D (OFF) | | | | | | | |
| ADG658 | 29 | | | | | pF typ | $f = 1\text{ MHz}$ |
| ADG659 | 15 | | | | | pF typ | $f = 1\text{ MHz}$ |

| Parameter | B Version | | Y Version | | Unit | Test Conditions/Comments |
|--------------------------------------|-----------|-------------------|--------------------|--|------------------|-------------------------------|
| | +25°C | -40°C to +85°C | -40°C to +125°C | | | |
| C _D , C _S (ON) | | | | | | |
| ADG658 | 30 | | | | pF typ | f = 1 MHz |
| ADG659 | 16 | | | | pF typ | f = 1 MHz |
| POWER REQUIREMENTS | | | | | | V _{DD} = 5.5 V |
| I _{DD} | 0.01 | | 1 | | μA typ μA max | Digital Inputs = 0 V or 5.5 V |

¹ Guaranteed by design; not subject to production test.

2.7 V TO 3.6 V SINGLE SUPPLY

$V_{DD} = 2.7$ to 3.6 V, $V_{SS} = 0$ V, $GND = 0$ V, unless otherwise noted.

Table 3.

| Parameter | B Version | | | Y Version | Unit | Test Conditions/Comments |
|--|-------------|-------------------|--------------------|--------------------|--------------|---|
| | +25°C | -40°C to +85°C | -40°C to +125°C | -40°C to +125°C | | |
| ANALOG SWITCH | | | | | | |
| Analog Signal Range | | | | 0 to V_{DD} | V | $V_{DD} = 2.7$ V, $V_{SS} = 0$ V |
| On Resistance (R_{ON}) | 185 | | | | Ω typ | $V_S = 0$ V to 2.7 V, $I_S = 0.1$ mA; see Figure 21 |
| | 300 | 350 | 400 | | Ω max | |
| On Resistance Match between | 2 | | | | Ω typ | $V_S = 1.5$ V, $I_S = 0.1$ mA |
| Channels (ΔR_{ON}) | 4.5 | 6 | 7 | | Ω max | |
| LEAKAGE CURRENTS | | | | | | |
| Source OFF Leakage I_S (OFF) | ± 0.005 | | | | nA typ | $V_{DD} = 3.3$ V |
| | ± 0.2 | | | ± 5 | nA max | $V_S = 1$ V/3 V, $V_D = 3$ V/1 V; see Figure 22 |
| Drain OFF Leakage I_D (OFF) | ± 0.005 | | | | nA typ | $V_S = 1$ V/3 V, $V_D = 3$ V/1 V; see Figure 23 |
| ADG658 | ± 0.2 | | | ± 5 | nA max | |
| ADG659 | ± 0.1 | | | ± 2.5 | nA max | |
| Channel ON Leakage I_D, I_S (ON) | ± 0.005 | | | | nA typ | $V_S = V_D = 1$ V or 3 V, see Figure 24 |
| ADG658 | ± 0.2 | | | ± 5 | nA max | |
| ADG659 | ± 0.1 | | | ± 2.5 | nA max | |
| DIGITAL INPUTS | | | | | | |
| Input High Voltage, V_{INH} | | | | 2.0 | V min | |
| Input Low Voltage, V_{INL} | | | | 0.5 | V max | |
| Input Current | | | | | | |
| I_{INL} or I_{INH} | 0.005 | | | | μ A typ | $V_{IN} = V_{INL}$ or V_{INH} |
| | | | | ± 1 | μ A max | |
| C_{IN} , Digital Input Capacitance | 2 | | | | pF typ | |
| DYNAMIC CHARACTERISTICS¹ | | | | | | |
| $t_{TRANSITION}$ | 200 | | | | ns typ | $R_L = 300$ Ω , $C_L = 35$ pF |
| | 370 | 440 | 490 | | ns max | $V_S = 1.5$ V; see Figure 25 |
| $t_{ON}(\overline{EN})$ | 230 | | | | ns typ | $R_L = 300$ Ω , $C_L = 35$ pF |
| | 370 | 440 | 490 | | ns max | $V_S = 1.5$ V; see Figure 27 |
| $t_{OFF}(\overline{EN})$ | 50 | | | | ns typ | $R_L = 300$ Ω , $C_L = 35$ pF |
| | 80 | 90 | 110 | | ns max | $V_S = 1.5$ V; see Figure 27 |
| Break-Before-Make Time Delay, t_{BBM} | 200 | | | | ns typ | $R_L = 300$ Ω , $C_L = 35$ pF |
| | | | | 10 | ns min | $V_{S1} = V_{S2} = 1.5$ V; see Figure 26 |
| Charge Injection | 1 | | | | pC typ | $V_S = 1.5$ V, $R_S = 0$ Ω , $C_L = 1$ nF; see Figure 28 |
| | 2 | | | | pC max | |
| Off Isolation | -90 | | | | dB typ | $R_L = 50$ Ω , $C_L = 5$ pF, $f = 1$ MHz; see Figure 29 |
| Channel-to-Channel Crosstalk | -90 | | | | dB typ | $R_L = 50$ Ω , $C_L = 5$ pF; $f = 1$ MHz; see Figure 31 |
| (ADG659) | | | | | | |
| -3 dB Bandwidth | | | | | | |
| ADG658 | 160 | | | | MHz typ | $R_L = 50$ Ω , $C_L = 5$ pF; see Figure 30 |
| ADG659 | 300 | | | | MHz typ | |
| C_S (OFF) | 5 | | | | pF typ | $f = 1$ MHz |
| C_D (OFF) | | | | | | |
| ADG658 | 29 | | | | pF typ | $f = 1$ MHz |
| ADG659 | 15 | | | | pF typ | $f = 1$ MHz |

| Parameter | B Version | | Y Version | Unit | Test Conditions/Comments |
|--------------------------------------|-----------|-------------------|--------------------|------------------|-------------------------------|
| | +25°C | -40°C to +85°C | -40°C to +125°C | | |
| C _D , C _S (ON) | | | | | |
| ADG658 | 30 | | | pF typ | f = 1 MHz |
| ADG659 | 16 | | | pF typ | f = 1 MHz |
| POWER REQUIREMENTS | | | | | V _{DD} = 3.6 V |
| I _{DD} | 0.01 | | 1 | μA typ μA max | Digital Inputs = 0 V or 3.6 V |

¹ Guaranteed by design; not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 4.

| Parameter | Rating |
|--|--|
| V_{DD} to V_{SS} | 13 V |
| V_{DD} to GND | -0.3 V to +13 V |
| V_{SS} to GND | +0.3 V to -6.5 V |
| Analog Inputs ¹ | $V_{SS} - 0.3\text{ V}$ to $V_{DD} + 0.3\text{ V}$ |
| Digital Inputs ¹ | GND - 0.3 V to $V_{DD} + 0.3\text{ V}$ or 10 mA, whichever occurs first |
| Peak Current, S or D (Pulsed at 1 ms, 10% duty cycle max) | 40 mA |
| Continuous Current, S or D | 20 mA |
| Operating Temperature Range | |
| Automotive (Y Version) | -40°C to +125°C |
| Industrial (B Version) | -40°C to +85°C |
| Storage Temperature Range | -65°C to +150°C |
| Junction Temperature | 150°C |
| θ_{JA} Thermal Impedance | |
| 16-Lead QSOP | 104°C/W |
| 16-Lead TSSOP | 150.4°C/W |
| 16-Lead LFCSP (4-Layer Board) | 70°C/W |
| Lead Temperature, Soldering | |
| Vapor Phase (60 sec) | 215°C |
| Infrared (15 sec) | 220°C |
| ESD | 5.5 kV |

¹ Over voltages at A_x , \overline{EN} , S, or D are clamped by internal diodes. Current must be limited to the maximum ratings.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device.

Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

Table 5. ADG658 Truth Table

| A2 | A1 | A0 | EN | Switch Condition |
|----------------|----------------|----------------|-----------|-------------------------|
| X ¹ | X ¹ | X ¹ | 1 | None |
| 0 | 0 | 0 | 0 | 1 |
| 0 | 0 | 1 | 0 | 2 |
| 0 | 1 | 0 | 0 | 3 |
| 0 | 1 | 1 | 0 | 4 |
| 1 | 0 | 0 | 0 | 5 |
| 1 | 0 | 1 | 0 | 6 |
| 1 | 1 | 0 | 0 | 7 |
| 1 | 1 | 1 | 0 | 8 |

¹X = Don't Care

Table 6. ADG659 Truth Table

| A1 | A0 | EN | On Switch Pair |
|----------------|----------------|-----------|-----------------------|
| X ¹ | X ¹ | 1 | None |
| 0 | 0 | 0 | 1 |
| 0 | 1 | 0 | 2 |
| 1 | 0 | 0 | 3 |
| 1 | 1 | 0 | 4 |

¹X = Don't Care

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

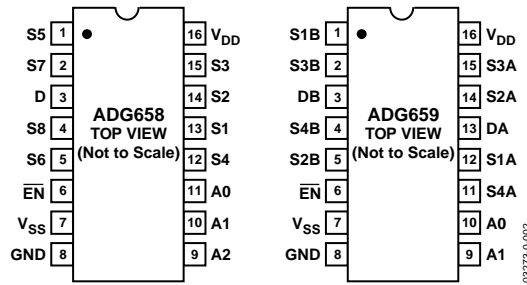
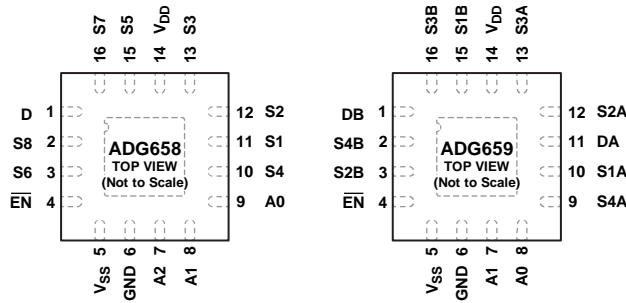


Figure 2. 16-Lead TSSOP/QSOP Pin Configuration



NOTES
 1. EXPOSED PAD. THE EXPOSED PAD MUST BE LEFT FLOATING.

Figure 3. 16-Lead, 4 mm x 4 mm LFCSP Pin Configuration

Table 7. Pin Function Descriptions

| Parameter | Description |
|-------------------|--|
| V _{DD} | Most Positive Power Supply Potential. |
| V _{SS} | Most Negative Power Supply Potential. |
| I _{DD} | Positive Supply Current. |
| I _{SS} | Negative Supply Current. |
| GND | Ground (0 V) Reference. |
| S | Source Terminal. Can be an input or output. |
| D | Drain Terminal. Can be an input or output. |
| A _x | Logic Control Input. |
| EN | Active Low Digital Input. When high, device is disabled and all switches are OFF. When low, A _x logic inputs determine ON switch. |
| EPAD (LFCSP Only) | Exposed Pad. The exposed pad must be left floating. |

TYPICAL PERFORMANCE CHARACTERISTICS

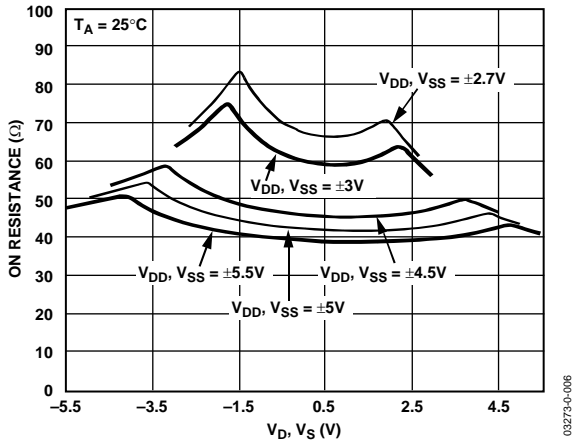


Figure 4. On Resistance vs. V_D (V_S) for Dual Supply

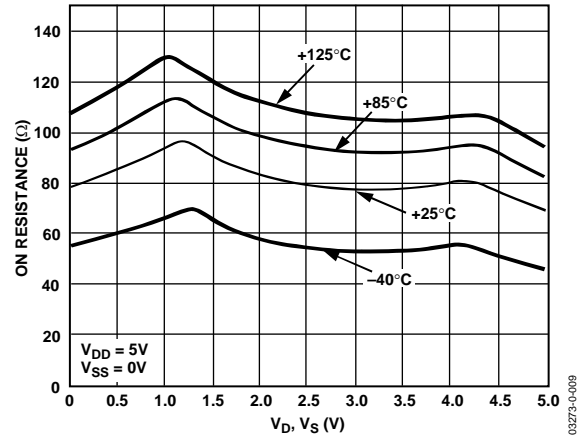


Figure 7. On Resistance vs. V_D (V_S) for Different Temperatures (Single Supply)

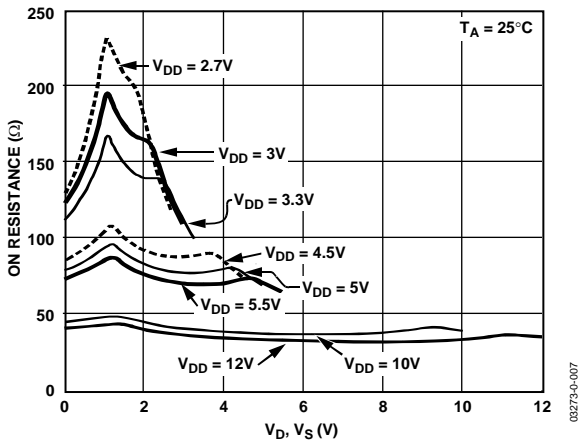


Figure 5. On Resistance vs. V_D (V_S) for Single Supply

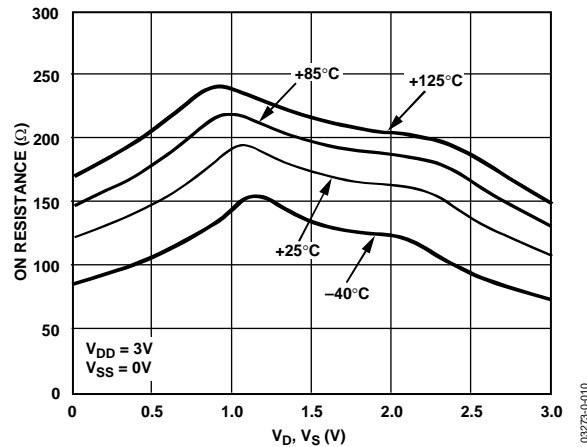


Figure 8. On Resistance vs. V_D (V_S) for Different Temperatures (Single Supply)

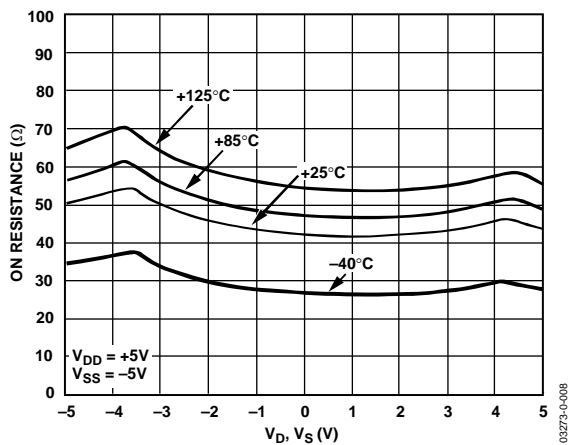


Figure 6. On Resistance vs. V_D (V_S) for Different Temperatures (Dual Supply)

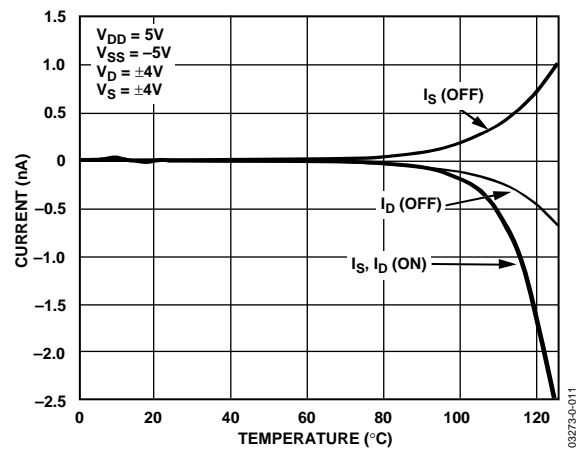


Figure 9. Leakage Current vs. Temperature (Dual Supply)

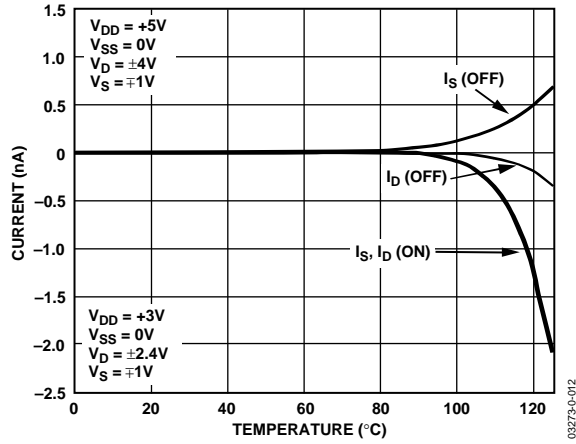


Figure 10. Leakage Current vs. Temperature (Single Supply)

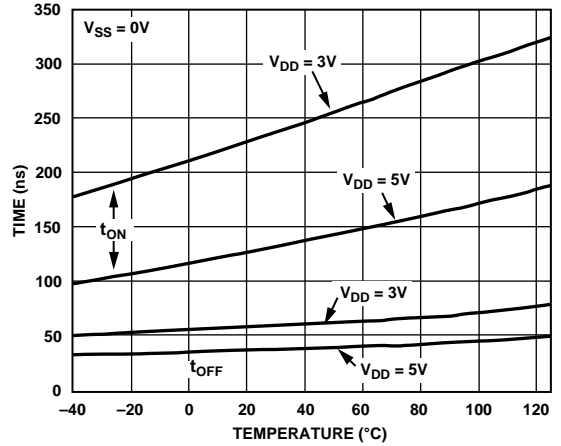


Figure 13. t_{ON}/t_{OFF} Times vs. Temperature (Single Supply)

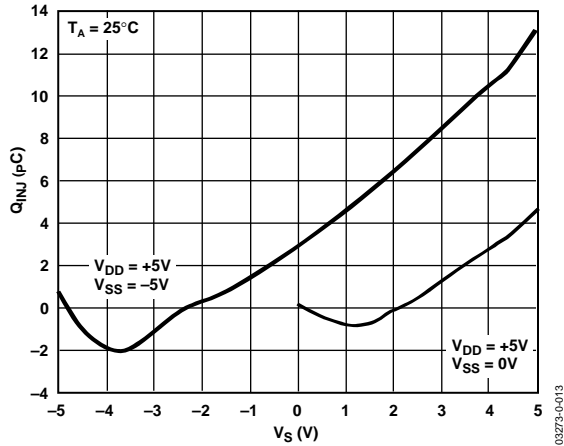


Figure 11. Charge Injection vs. Source Voltage

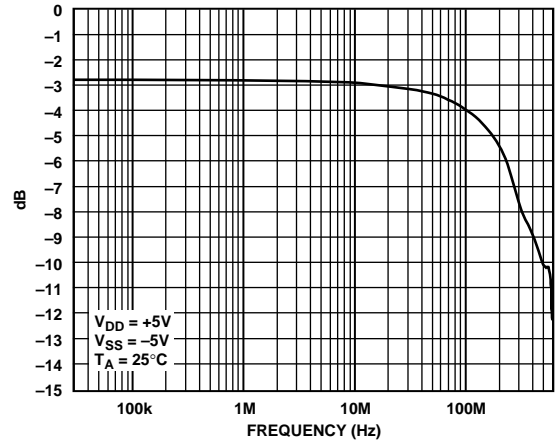


Figure 14. ON Response vs. Frequency (ADG658)

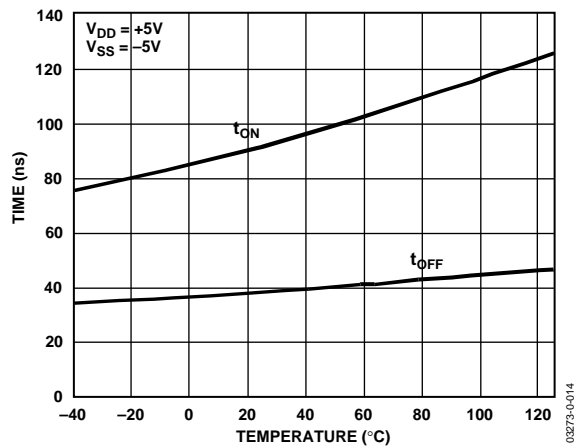


Figure 12. t_{ON}/t_{OFF} Times vs. Temperature (Dual Supply)

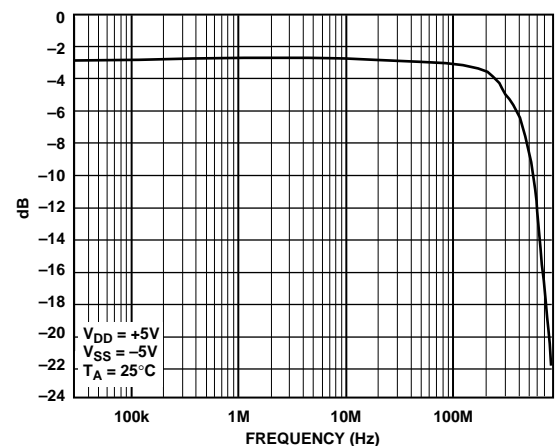


Figure 15. ON Response vs. Frequency (ADG659)

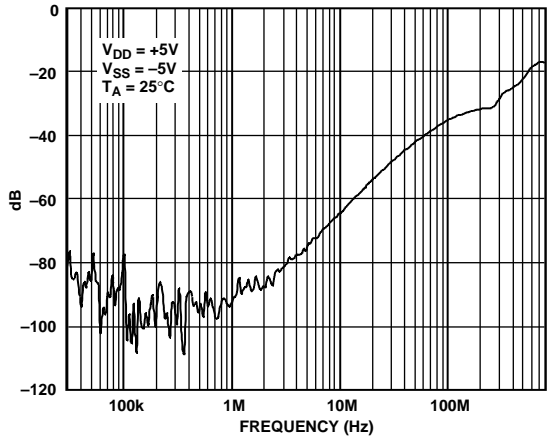


Figure 16. OFF Isolation vs. Frequency

03273-0-018

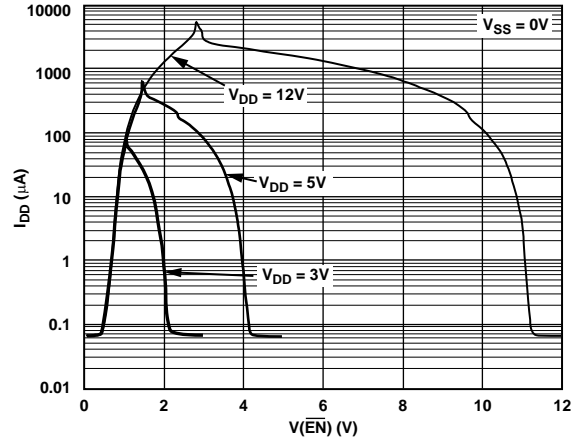


Figure 19. V_{DD} Current vs. Logic Level

03273-0-021

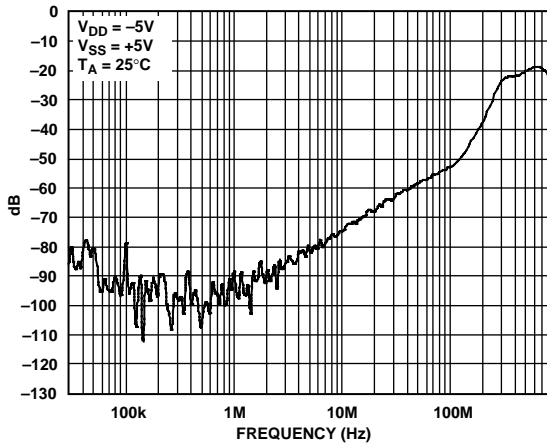


Figure 17. Crosstalk vs. Frequency

03273-0-019

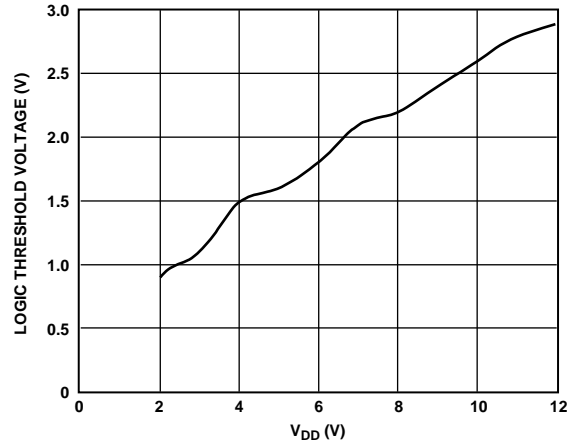


Figure 20. Logic Threshold Voltage vs. Supply Voltage

03273-0-022

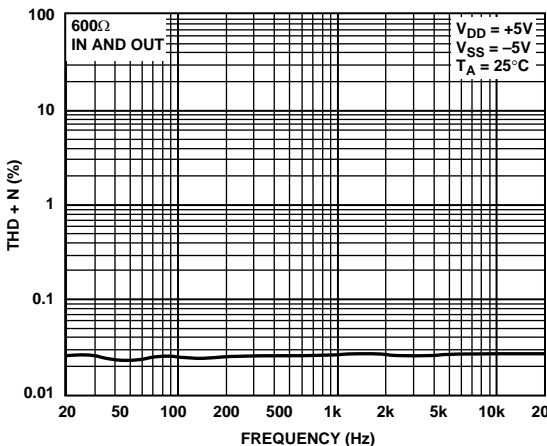


Figure 18. THD + Noise

03273-0-020

TERMINOLOGY

V_D (V_S)

Analog Voltage on Terminals D, S.

R_{ON}

Ohmic Resistance between D and S.

ΔR_{ON}

On Resistance Match between Any Two Channels, i.e., R_{ONmax} – R_{ONmin} .

$R_{FLAT(ON)}$

Flatness is defined as the difference between the maximum and minimum value of ON Resistance as measured over the specified analog signal range.

I_S (OFF)

Source Leakage Current with the Switch OFF.

I_D (OFF)

Drain Leakage Current with the Switch OFF.

I_D, I_S (ON)

Channel Leakage Current with the Switch ON.

V_{INL}

Maximum Input Voltage for Logic 0.

V_{INH}

Minimum Input Voltage for Logic 1.

I_{INL} (I_{INH})

Input Current of the Digital Input.

C_S (OFF)

OFF Switch Source Capacitance. Measured with reference to ground.

C_D (OFF)

OFF Switch Drain Capacitance. Measured with reference to ground.

C_D, C_S (ON)

ON Switch Capacitance. Measured with reference to ground.

C_{IN}

Digital Input Capacitance.

t_{ON}

Delay between Applying the Digital Control Input and the Output Switching ON. See Figure 27.

t_{OFF}

Delay between Applying the Digital Control Input and the Output Switching OFF.

t_{BEM}

ON Time. Measured between 80% points of both switches when switching from one address state to another.

Charge Injection

Measure of the Glitch Impulse Transferred from the Digital Input to the Analog Output during Switching.

Off Isolation

Measure of Unwanted Signal Coupling through an OFF Switch.

Crosstalk

Measure of Unwanted Signal Coupled through from One Channel to Another as a Result of Parasitic Capacitance.

Bandwidth

The Frequency at which the Output is Attenuated by 3 dB.

On Response

The Frequency Response of the ON Switch.

Insertion Loss

The Loss Due to the ON Resistance of the Switch.

TEST CIRCUITS

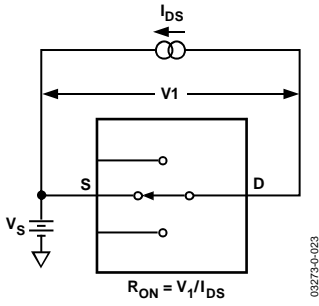


Figure 21. ON Resistance

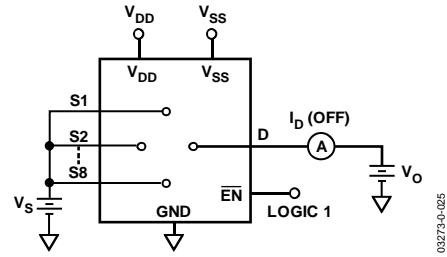


Figure 23. I_D (OFF)

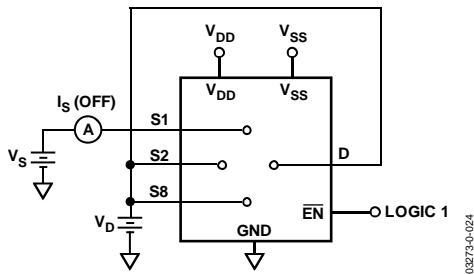


Figure 22. I_S (OFF)

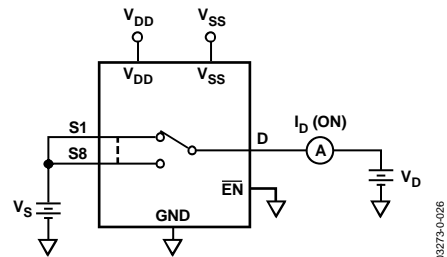
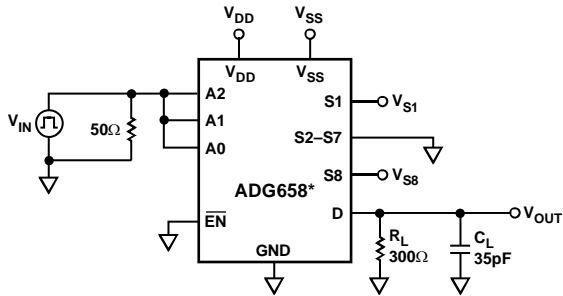


Figure 24. I_D (ON)



* SIMILAR CONNECTION FOR ADG659

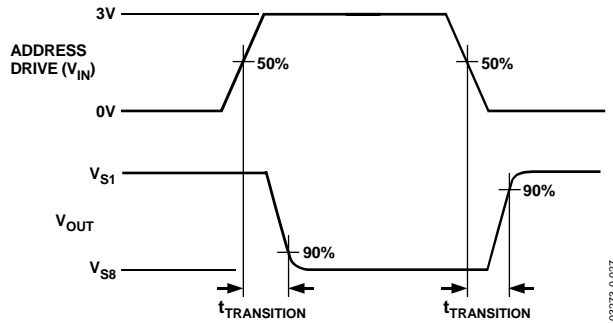
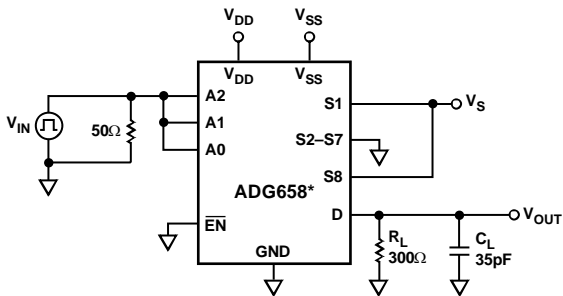


Figure 25. Switching Time of Multiplexer, t_{TRANSITION}



* SIMILAR CONNECTION FOR ADG659

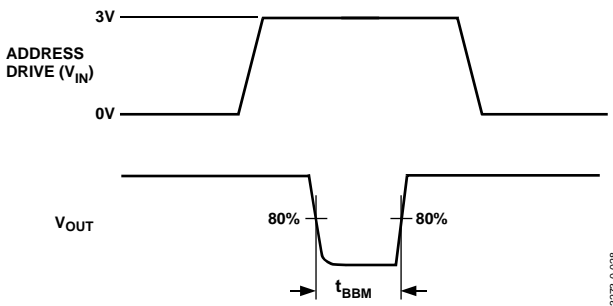


Figure 26. Break-Before-Make Delay, t_{BBM}

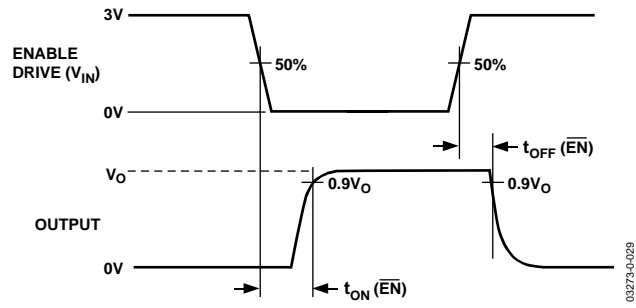
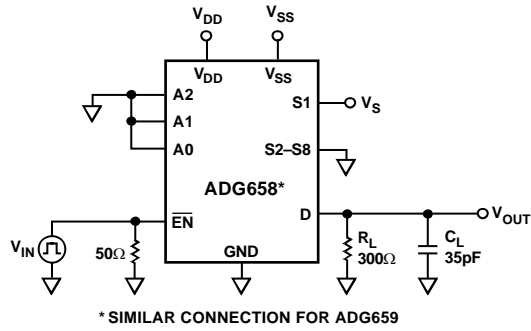


Figure 27. Enable Delay, $t_{ON}(\overline{EN})$, $t_{OFF}(\overline{EN})$

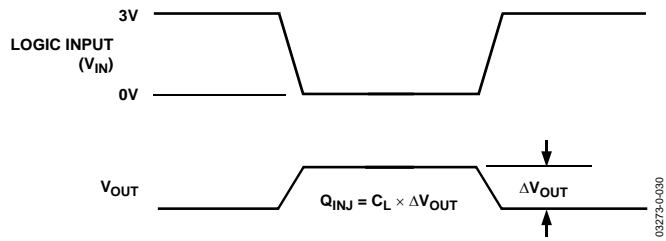
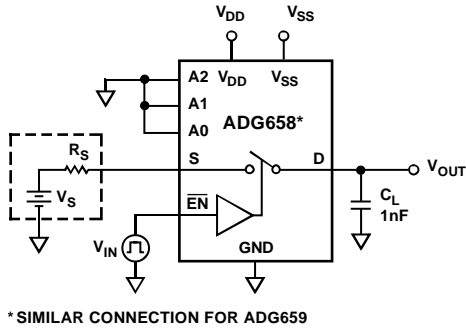


Figure 28. Charge Injection

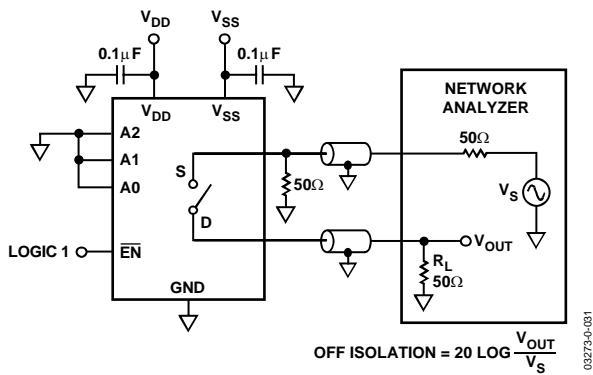


Figure 29. Off Isolation

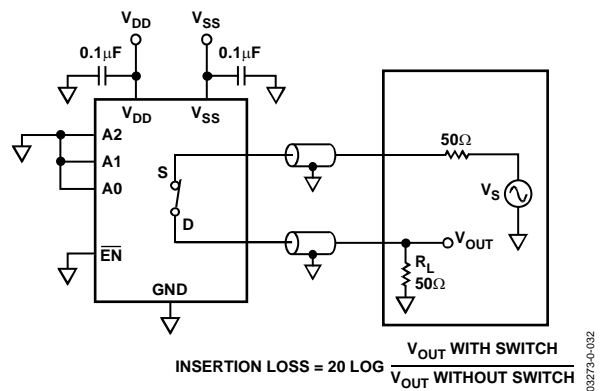
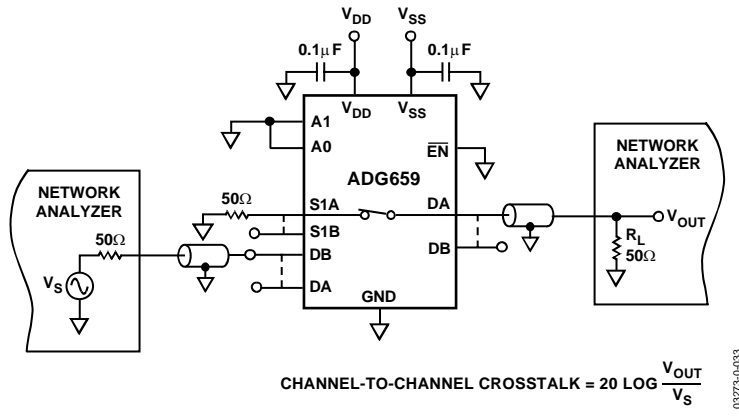


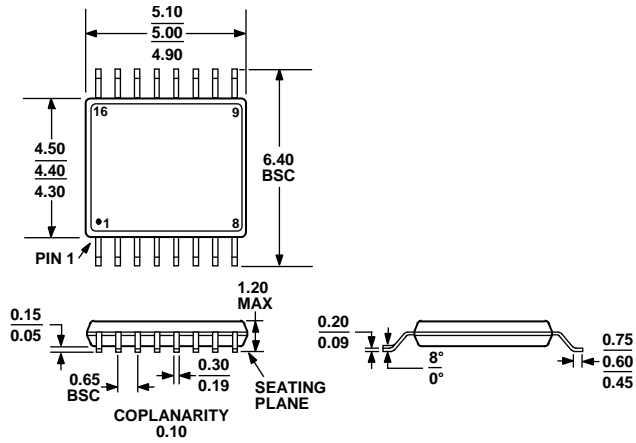
Figure 30. Bandwidth



03273-0-033

Figure 31. Channel-to-Channel Crosstalk

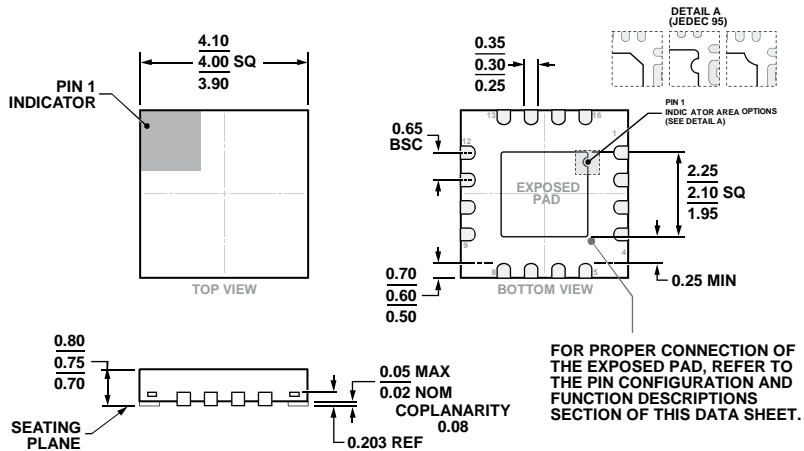
OUTLINE DIMENSIONS



COMPLIANT TO JEDEC STANDARDS MO-153-AB

Figure 32. 16-Lead Thin Shrink Small Outline Package [TSSOP] (RU-16)

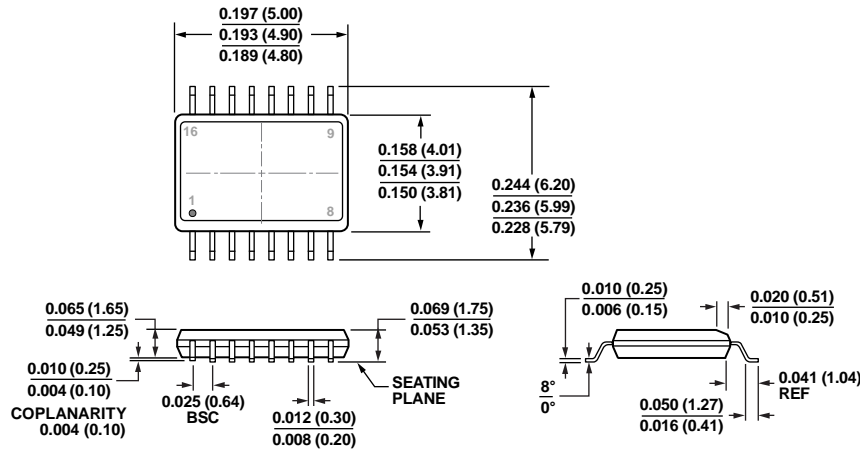
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-220-WGGC.

Figure 33. 16-Lead Lead Frame Chip Scale Package [LFCSP] 4 mm x 4 mm Body and 0.75 mm Package Height (CP-16-23)

Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-137-AB
 CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS
 (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR
 REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN.

Figure 34. 16-Lead Shrink Small Outline Package [QSOP]
 (RQ-16)
 Dimensions shown in inches and (millimeters)

09-12-2014-A

ORDERING GUIDE

| Model ^{1, 2} | Temperature Range | Package Description | Package Option |
|-----------------------|-------------------|---|----------------|
| ADG658YRU | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG658YRU-REEL7 | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG658YRUZ | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG658YRUZ-REEL7 | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG658YCPZ | -40°C to +85°C | 16-Lead Lead Frame Chip Scale Package [LFCSP] | CP-16-23 |
| ADG658YCPZ-REEL7 | -40°C to +85°C | 16-Lead Lead Frame Chip Scale Package [LFCSP] | CP-16-23 |
| ADG658YRQ | -40°C to +125°C | 16-Lead Shrink Small Outline Package [QSOP] | RQ-16 |
| ADG658YRQZ | -40°C to +125°C | 16-Lead Shrink Small Outline Package [QSOP] | RQ-16 |
| ADG658YRQZ-REEL7 | -40°C to +125°C | 16-Lead Shrink Small Outline Package [QSOP] | RQ-16 |
| ADW54003-0 | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADW54003-0RL7 | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG659YRU | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG659YRUZ | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG659YRUZ-REEL7 | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG659YRUZ-REEL7 | -40°C to +125°C | 16-Lead Thin Shrink Small Outline Package [TSSOP] | RU-16 |
| ADG659YCPZ | -40°C to +85°C | 16-Lead Lead Frame Chip Scale Package [LFCSP] | CP-16-23 |
| ADG659YCPZ-REEL7 | -40°C to +85°C | 16-Lead Lead Frame Chip Scale Package [LFCSP] | CP-16-23 |
| ADG659YRQZ | -40°C to +125°C | 16-Lead Shrink Small Outline Package [QSOP] | RQ-16 |

¹ Z = RoHS Compliant Part.
² W = Qualified for Automotive Applications.

AUTOMOTIVE PRODUCTS

The ADW54003 models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А